

PAM8902A
**30 V_{PP} MONO CLASS-D AUDIO AMPLIFIER FOR
PIEZO/CERAMIC SPEAKERS WITH ANTI-SATURATION**
Description

The PAM8902A is a mono, Class-D audio amplifier with integrated boost convertor designed for piezo and ceramic speakers. The PAM8902A is capable for driving a ceramic/piezo speaker with 30V_{PP}(0.6Vrms) from a 3.6V power supply. The PAM8902A's boost converter operates at a fixed frequency of 1.5MHz and provides a 17.5V supply with a minimum number of external components. The three gain mode of 18dB, 22dB and 26dB is easy for using. PAM unique anti-saturation technology which detects output signal clip due to the over level input signal suppress the output signal clip automatically. PAM8902A features an integrated audio low pass filter that rejects high frequency noise, thus improving audio fidelity. PAM8902A also provides thermal, over current, under and over voltage protection.

The PAM8902A is available in a 16-ball 1.95mm x 1.95mm CSP package and 16-pin QFN4x4 package.

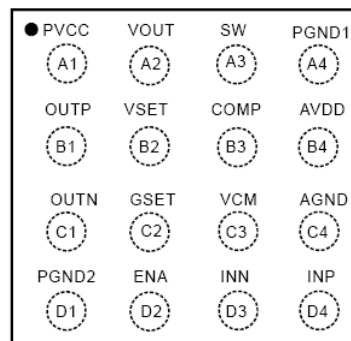
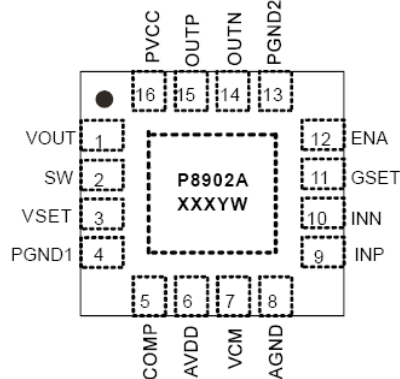
Features

- Supply Voltage Range from 2.7V to 5.5V package.
- 30V_{PP} Output Load Voltage from a 2.7V Supply
- Integrated Boost Converter Generates 17.5V Supply
- Programmable Soft-Start
- Unique Anti-Saturation Function
- Small Boost Converter Inductor
- Selectable Gain of 18dB, 22dB, and 26dB
(Refer to "Application Notes")
- Selectable Boost output voltage of 8V, 12V, and 17.5V
- Low Shutdown Current: <1μA
- Build in Thermal, OCP, UVLO, OVP
- Available in Space Saving Packages:
 - 16-ball 1.95mm x 1.95mm CSP package
 - 16-pin QFN4x4 package

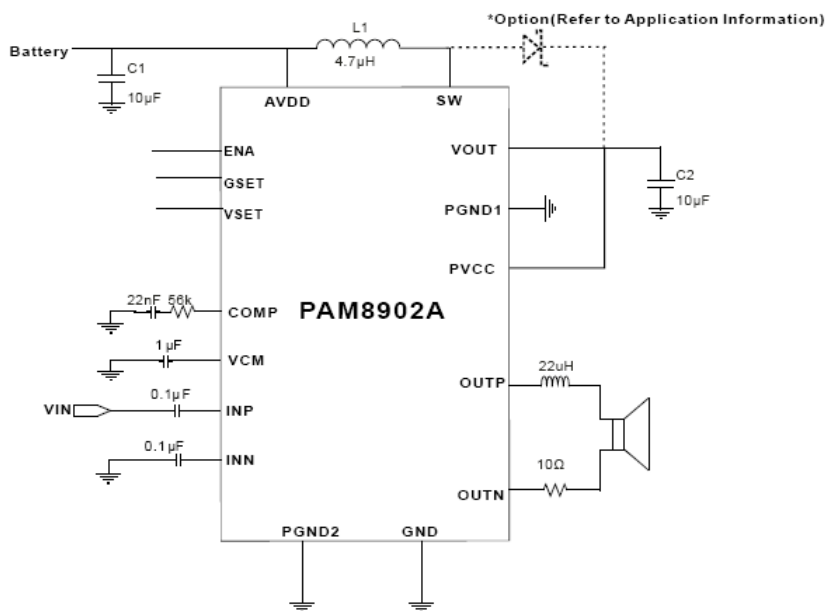
Applications

- Wireless or Cellular Handsets
- Portable DVD Player
- Personal Digital Assistants (PDAs)
- Electronic Dictionaries
- Digital Still Cameras

Pin Assignments

16 Ball CSP
Top View

Top View
QFN 4X4 16L


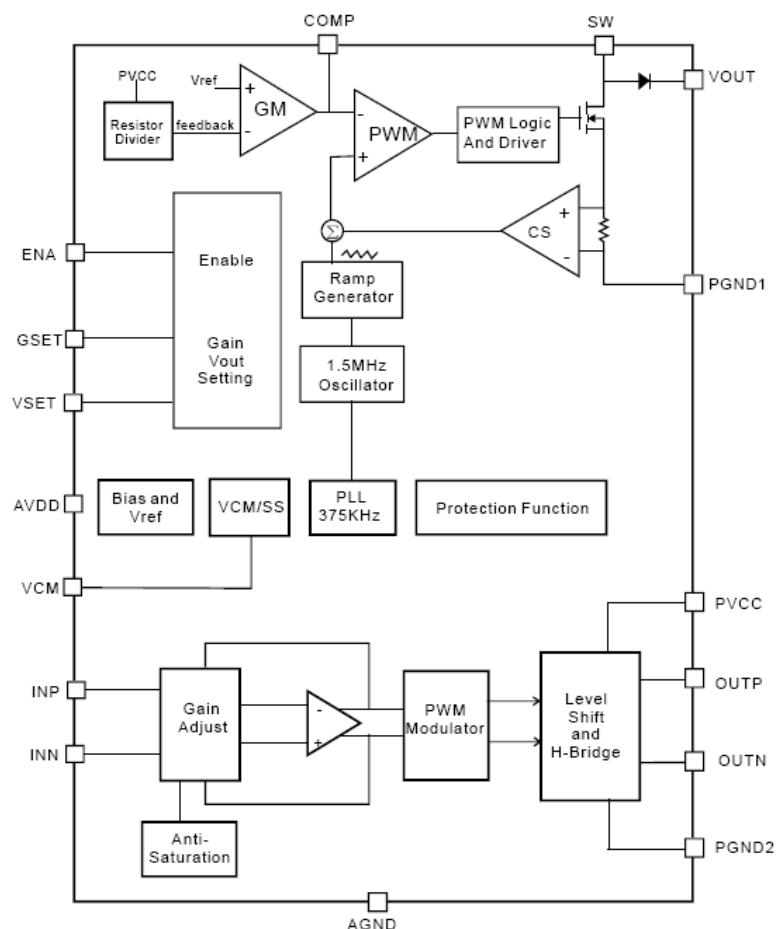
Typical Applications Circuit



Pin Descriptions

Bump (CSP)	Pin Number (QFN)	Pin Name	Function
A1	13	PVCC	Audio Amplifier Power Supply
A2	1	VOUT	Boost Converter Output
A3	2	SW	Boost Converter Switching Node
A4	4	PGND1	Boost Converter Power Ground
B1	15	OUTP	Positive Differential Audio Output
B2	3	VSET	Boost Converter Output Voltage Setting(8V,12V,17.5V)
B3	5	COMP	Boost Converter Compensation
B4	6	AVDD	Power Supply
C1	14	OUTN	Negative Differential Audio Output
C2	11	GSET	AmplifierGain Setting. (Refer to "Application Notes")
C3	7	VCM	Common Mode Bypass Cap
C4	8	AGND	Analog Ground
D1	13	PGND2	Class D PowerGround
D2	12	ENA	Whole Chip Enable
D3	10	INN	Negative Differential Audio Input
D4	9	INP	Positive Differential Audio Input

Functional Block Diagram



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

These are stress ratings only and functional operation is not implied. Exposure to absolute maximum ratings for prolonged time periods may affect device reliability. All voltages are with respect to ground.

Parameter	Rating	Unit
Supply Voltage	6.0	V
Input Voltage	-0.3 to V _{DD} +0.3	
Maximum Junction Temperature	+150	°C
Storage Temperature	-65 to +150	
Soldering Temperature	250, 10 sec	

Recommended Operating Conditions (@T_A = +25°C, unless otherwise specified.)

Parameter	Rating	Unit
Supply Voltage Range	2.7 to 5.5	V
Ambient Temperature Range	-40 to +85	°C
Junction Temperature Range	-40 to +125	°C

Thermal Information

Parameter	Package	Symbol	Max	Unit
Thermal Resistance (Junction to Ambient)	CSP	θ_{JA}	90 – 220	°C/W
	QFN4x4-16		37	
Thermal Resistance (Junction to Case)	CSP	θ_{JC}	75	
	QFN4x4-16		2	

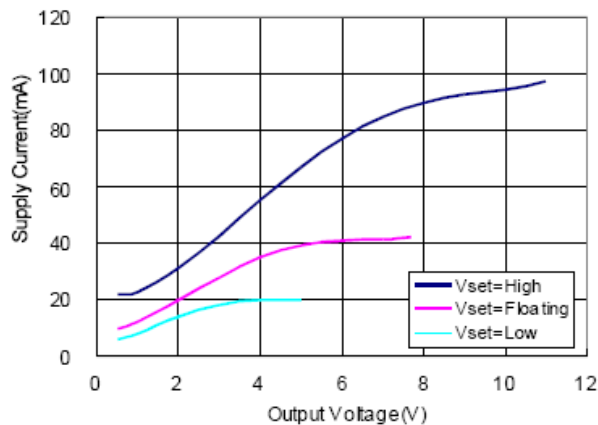
Electrical Characteristics

(@T_A = +25°C, V_{DD} = 3.6V, C_L = 1μF, V_{SET} floating, R_{LOAD} = 10Ω, L_{LOAD} = 22μH with external schottky diodes, unless otherwise specified.)

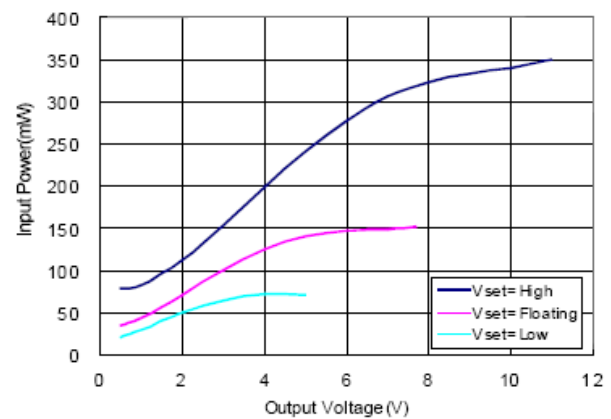
Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Input Voltage	V _{DD}		2.7		5.5	V
Quiescent Current	I _Q	EN > 1.2V, V _{SET} = High		30	48	mA
		EN > 1.2V, V _{SET} = Floating		10	18	
		EN > 1.2V, V _{SET} = GND		5	12	
Shutdown Current	I _{SD}	EN = 0V		0.1	1	μA
Wake-Up Time	T _{WU}	EN from Low to High		40		mS
Chip Enable	V _{EH}		1.2			V
Chip Disable	V _{EL}				0.4	
GSET/ VSET High	V _H		V _{DD} -0.5		V _{DD}	V
GSET/ VSET Floating	V _F		1		V _{DD} -1	
GSET/ VSET Low	V _L		0		0.5	
Under Voltage Lockout Threshold	UVLO	V _{DD} from High to Low		2.2		V
Under Voltage Lockout Hysteresis	UVLO(H)	V _{DD} from Low to High		0.2		
Thermal Shutdown Threshold	OTP			150		°C
Thermal Shutdown Lockout Hysteresis	OTP(H)			30		°C
Boost Converter						
Output Voltage	V _{O1}	V _{SET} = Low, No Load	7.2	8.0	8.8	V
	V _{O2}	V _{SET} = Floating, No Load	10.8	12.0	13.2	V
	V _{O3}	V _{SET} = High, No Load	16.0	17.5	19.0	V
Current Limit	C _L	Average Input Current		0.8		A
Lowside MOSFET R _{DS(ON)}	R _{LS}	I _O = 50mA		0.5		Ω
Boost Switching Frequency	f _{OSCB}		1.1	1.5	1.9	MHz
Over Voltage Protection Threshold	V _{OVP}			18		V
Class D						
Class D Amplifier Switching Frequency	f _{OSCD}	Input AC-GND	225	375	475	KHz
Common Mode Reject Ratio	CMRR	V _{IN} = ±100mV, V _{DD} = 3.6V		60		dB
Output Offset Voltage	V _{OS}	Output Offset Voltage		5	50	mV
R _{DS(ON)}	R _P	High Side		1.5		Ω
		Low Side		0.6		Ω
Closed-Loop Voltage Gain	A _{V1}	G _{SET} = High, V _O = 1V _{RMS}	25	26	27	dB
	A _{V2}	G _{SET} = Floating, V _O = 1V _{RMS}	21	22	23	
	A _{V3}	G _{SET} = Low, V _O = 1V _{RMS}	17	18	19	
Power Supply Reject Ratio	PSRR	200m V _{PP} Supply Ripple @ 217Hz		70		dB
Total Harmonic Distortion Plus Noise	THD+N	V _O = 5V _{RMS}		0.3		%
Signal to Noise Ratio	SNR	Input AC Ground, A-Weighting		90		dB

Typical Performance Characteristics (@ $T_A = +25^\circ\text{C}$, $V_{DD} = 3.6\text{V}$, $C_L = 1\mu\text{F}$, $L = 4.7\mu\text{H}$, V_{SET} floating, $R_{LOAD} = 10\Omega$, $L_{LOAD} = 22\mu\text{H}$, with external schottky diode, unless otherwise specified.)

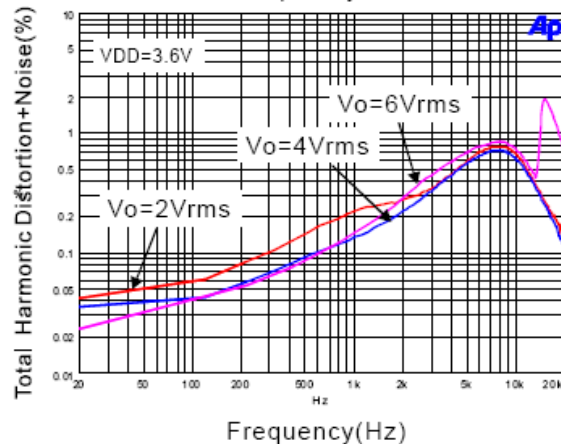
1. Supply Current VS Output Voltage ($V_o=8\text{V}$)



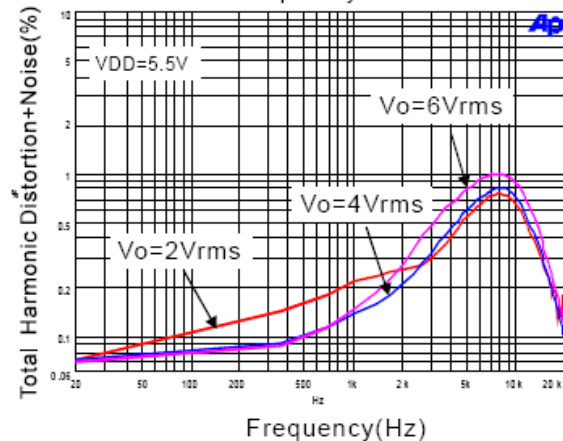
2. Input Power VS Output Voltage ($V_o=8\text{V}$)



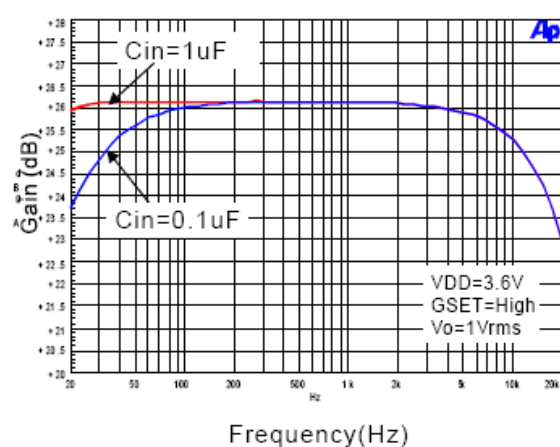
3. THD+N VS Frequency



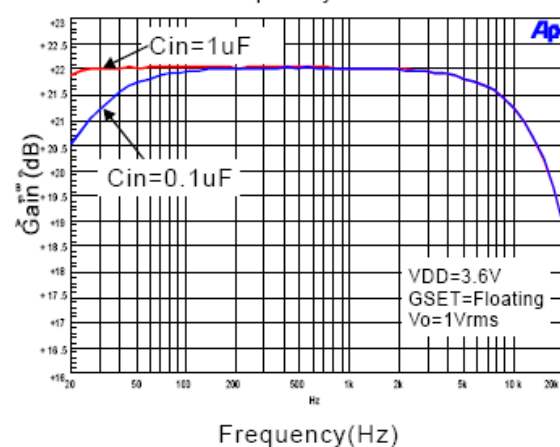
4. THD+N VS Frequency



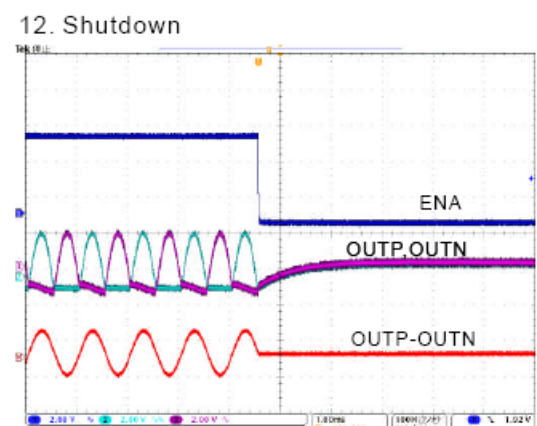
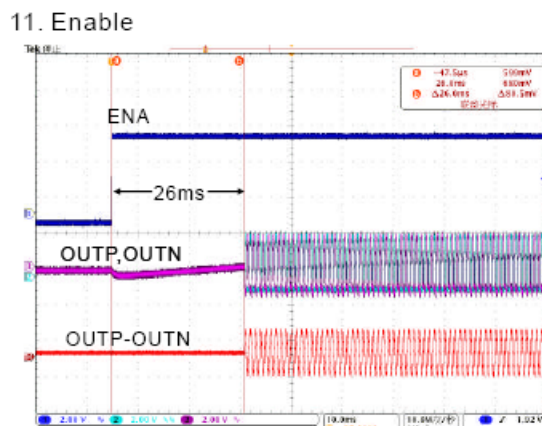
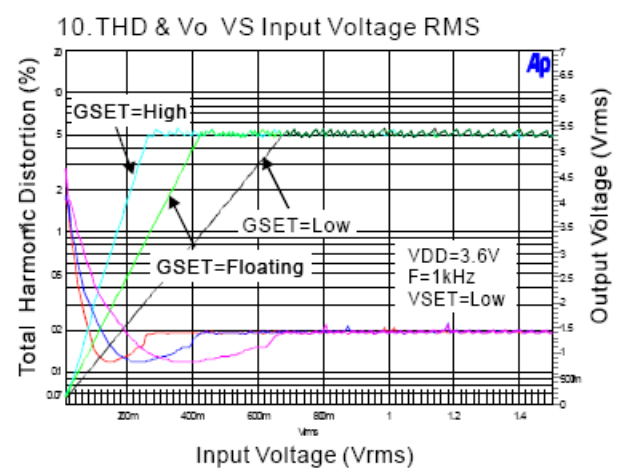
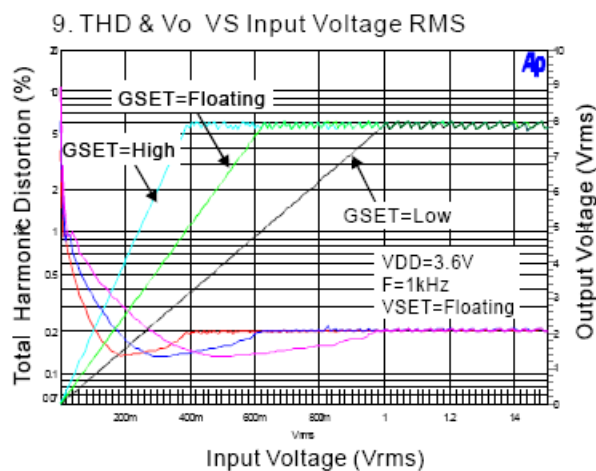
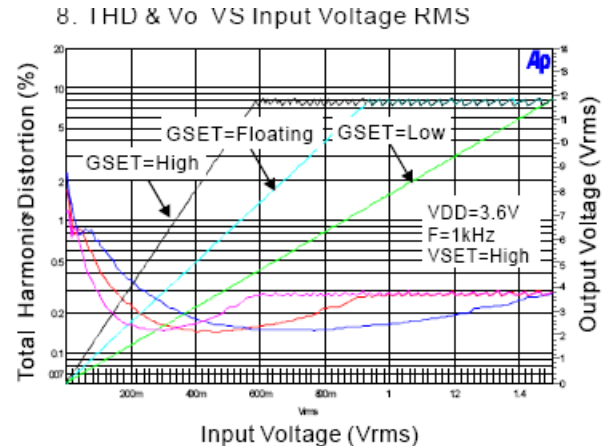
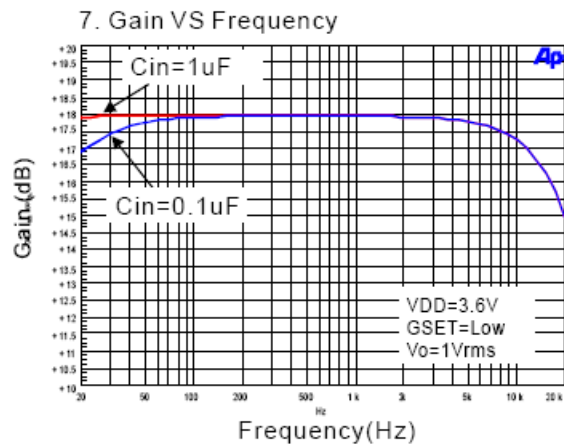
5. Gain VS Frequency



6. Gain VS Frequency



Typical Performance Characteristics (cont.) (@ $T_A = +25^\circ\text{C}$, $V_{DD} = 3.6\text{V}$, $C_L = 1\mu\text{F}$, $L = 4.7\mu\text{H}$, V_{SET} floating, $R_{LOAD} = 10\Omega$, $L_{LOAD} = 22\mu\text{H}$, with external schottky diode, unless otherwise specified.)



Application Information

Select Boost Converter Output Voltage

The V_{SET} pin sets the boost converter output voltage to 8V, 12V or 17.5V. V_{SET} pin configuration table as below:

V_{SET} Pin Configuration	Min	Max	PVCC Voltage	Audio Amplifier Maximum Output Voltage
High	$AVDD - 0.5$	$AVDD$	17.5V	11 V_{RMS} ($V_{PP} = 31.1V$)
Floating	1V	$AVDD - 1V$	12V	8 V_{RMS} ($V_{PP} = 22.6V$)
Low	GND	0.5V	8V	5 V_{RMS} ($V_{PP} = 14.1V$)

Gain Setting and Input Resistance (R_I)

Gain setting function is only available in disable condition ($ENA = low$) and need to follow the sequence as pull ENA to low (disable the IC) first, and change the G_{SET} voltage between high, floating, low, then pull ENA to high (enable the IC).

The input resistors ($R_I = R_{IN} + R_{EX}$) set the gain of the amplifier according to Equation 1 when anti-saturation is inactive.

$$G = 20 \text{ Log } [12.8 * R_F / (R_{IN} + R_{EX})] \text{ (dB)}$$

G_{SET}	R_{IN}	R_{FB}
High	77.4k Ω	122.6k Ω
Floating	100k Ω	100k Ω
Low	122.6k Ω	77.4k Ω

Where R_{IN} is a 77.4k Ω internal resistor, R_{EX} is the external input resistor, R_F is a 122.6k Ω internal resistor. Resistor matching is very important in fully differential amplifiers. The balance of the output on the reference voltage depends on matched ratios of the resistors. CMRR, PSRR, and cancellation of the second harmonic distortion diminish if resistor mismatch occurs. Therefore, it is recommended to use 1% tolerance resistors or better to keep the performance optimized. Matching is more important than overall tolerance. Resistor arrays with 1% matching can be used with a tolerance greater than 1%.

Place the input resistors very close to the PAM8902A to limit noise injection on the high-impedance nodes. For optimal performance the gain should be set to lower. Lower gain allows the PAM8902A to operate at its best, and keeps a high voltage at the input making the inputs less susceptible to noise. In addition to these features, higher value of R_I minimizes pop noise.

Anti-Saturation/Clipping Function

The anti-saturation circuitry detects the duty cycle of the PWM output. When the output starts to exhibit clipping, the gain is automatically decreased with an attack time of 100 μ s per step a release time of 186ms per step. The following table describes the operation:

Variable	Description	Value
Gain	The original gain of the device when the Anti-saturation is inactive.	26dB ($G_{SET} = High$) 22dB ($G_{SET} = Floating$) 18dB ($G_{SET} = Low$)
Attenuation Range	The gain control range when anti-saturation is active.	-26dB ($G_{SET} = High$) -22dB ($G_{SET} = Floating$) -18dB ($G_{SET} = Low$)
Step Size	Gain adjust step size.	0.25dB/Step
Attack Time	The minimum time between two gain decrements.	100 μ s
Release Time	The minimum time between two gain increments.	186ms

Application Information (cont.)

Input Capacitors (C_I)

In the typical application, an input capacitor, C_I , is required to allow the amplifier to bias the input signal to the proper DC level for optimum operation. In this case, C_I and the minimum input impedance R_I form a high-pass filter with the corner frequency determined in the follow equation:

$$f_C = \frac{1}{2\pi R_I C_I}$$

It is important to consider the value of C_I as it directly affects the low frequency performance of the circuit. For example, when R_I is 150k and the specification calls for a flat bass response are down to 150Hz.

Equation is reconfigured as followed:

$$C_I = \frac{1}{2\pi R_{IFC}}$$

When input resistance variation is considered, the C_I is 7nF, so one would likely choose a value of 10nF. A further consideration for this capacitor is the leakage path from the input source through the input network (C_I , R_I + R_F) to the load. This leakage current creates a DC offset voltage at the input to the amplifier that reduces useful headroom, especially in high gain applications. For this reason, a low-leakage tantalum or ceramic capacitor is the best choice. When polarized capacitors are used, the positive side of the capacitor should face the amplifier input in most applications as the DC level is held at $V_{DD}/2$, which is likely higher than the source DC level. Please note that it is important to confirm the capacitor polarity in the application.

Decoupling Capacitor

The PAM8902 is a high-performance CMOS audio amplifier that requires adequate power supply decoupling to ensure the output total harmonic distortion (THD) as low as possible.

The optimum decoupling is achieved by using two different types of capacitors that target on different types of noise on the power supply leads. For higher frequency transients, spikes, or digital hash on the line, a good low equivalent series-resistance (ESR) ceramic capacitor, typically 1μF is placed as close as possible to the device AVDD pin for the best operation. For filtering lower frequency noise signals, a large ceramic capacitor of 10μF or greater placed near the AVDD supply trace is recommended.

External Schottky Diode

Use external schottky diode can get the best driving capability and efficiency.

Since internal power diode has limited driving capability, only in following conditions customer can remove the external schottky diode to reduce the cost.

1. V_{SET} = Low or Floating and C_L less than 1μF.
2. The signal frequency less than 4KHz.
3. Haptic application (50–500Hz).

Shutdown Operation

In order to reduce power consumption while not in use, the PAM8902A contains shutdown circuitry amplifier off when a logic low is placed on the ENA pin. By switching the ENA pin connected to GND, the PAM8902A supply current draw will be minimized in idle mode.

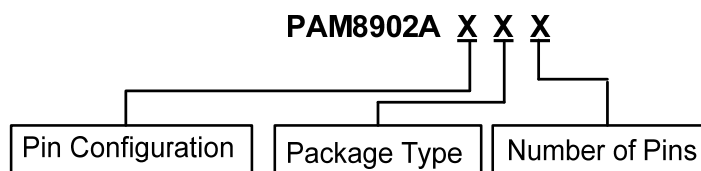
Under-Voltage Lock-Out (UVLO)

The PAM8902A incorporates circuitry designed to detect supply voltage. When the supply voltage drops to 2.2V or below, the PAM8902A goes into a state of shutdown, and the device comes out of its shutdown state and restore to normal function only when reset the power supply or ENA pin.

Over-Temperature Protection (OTP)

Thermal protection on the PAM8902A prevents the device from damage when the internal die temperature exceeds +150°C. There is a 15°C tolerance on this trip point from device to device. Once the die temperature exceeds the set point, the device will enter the shutdown state and the outputs are disabled, in this condition both OUP and OUTN will become high impedance. This is not a latched fault. The thermal fault is cleared once the temperature of the die decreased by 30°C. This large hysteresis will prevent motor boating sound well and the device begins normal operation at this point with no external system interaction.

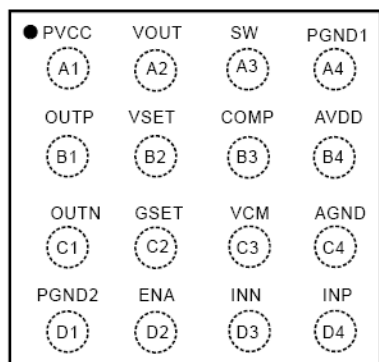
Ordering Information



Part Number	Part Marking	Package Type	Standard Package
PAM8902AZER	BN YW	CSP-16L	3000Units/Tape&Reel
PAM8902AKER	P8902A XXXYW	QFN4x4-16L	3000Units/Tape&Reel

Marking Information

16 Ball CSP
Top View

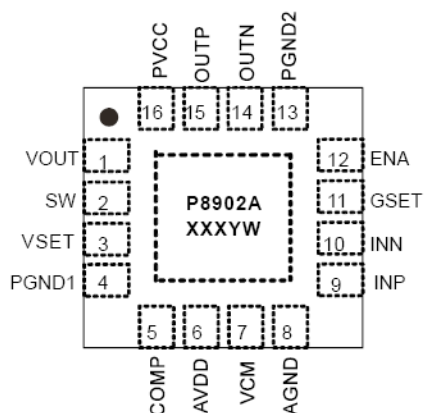


Marking

BN
YW

BN: Product Code of PAM8902A
Y: Year
W: Week

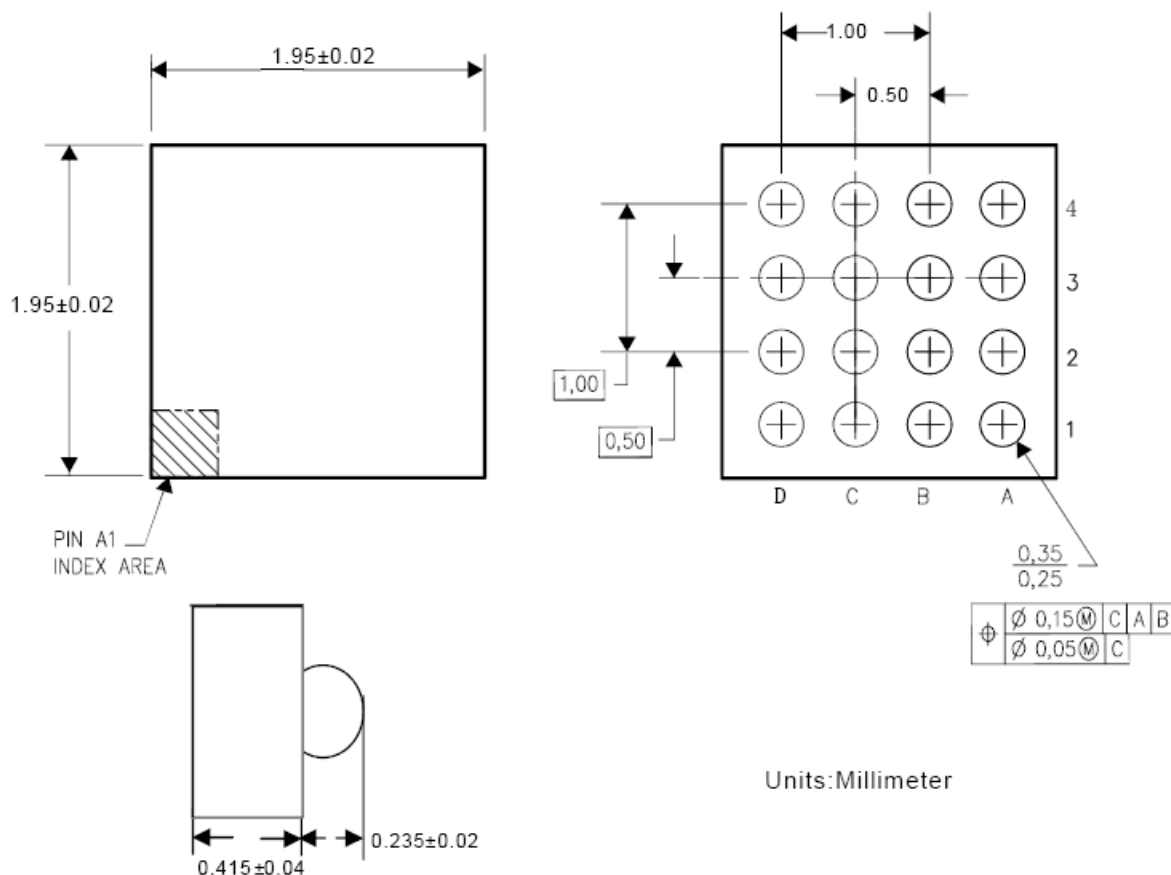
Top View
QFN 4X4 16L



Y: Year
W: Week
X: Internal Code

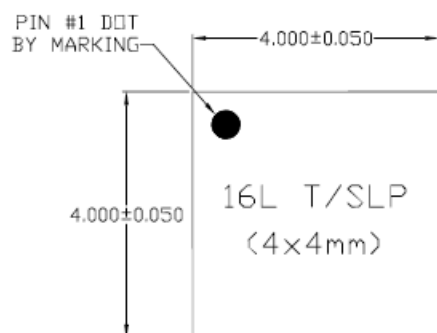
Package Outline Dimensions (All dimensions in mm.)

CSP-16

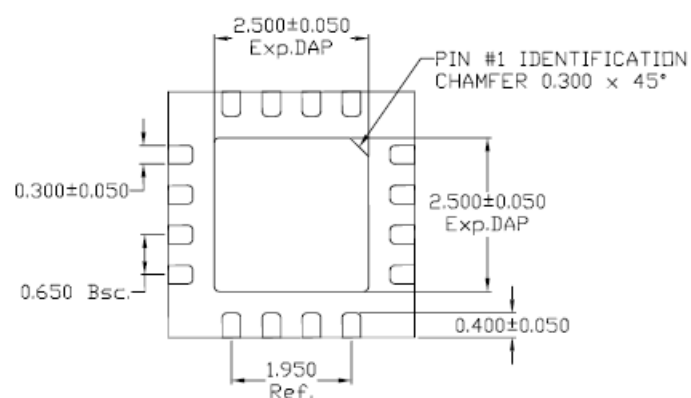


Package Outline Dimensions (cont.) (All dimensions in mm.)

QFN4x4-16



TOP VIEW

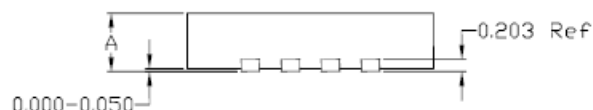


BOTTOM VIEW

NOTE:

1) TSLP AND SLP SHARE THE SAME EXPOSE OUTLINE
BUT WITH DIFFERENT THICKNESS:

A			TSLP	SLP
	MAX.		0.800	0.900
	NOM.		0.750	0.850
	MIN.		0.700	0.800



SIDE VIEW

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